N-CHANNEL ENHANCEMENT MODE MOSFET

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NEW PRODUCT

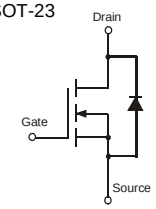
Features

- Low On-Resistance
  - 29mΩ @V_{GS} = 4.5V
  - 50mΩ @V_{GS} = 2.5V
  - 100mΩ @V_{GS} = 2.0V
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- **Lead, Halogen and Antimony Free, RoHS Compliant**
- **"Green" Device (Notes 2, 3 and 6)**
- **Qualified to AEC-Q101 Standards for High Reliability**

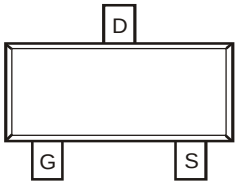
Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminal Connections: See Diagram
- Terminals: Finish — Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.008 grams (approximate)

TOP VIEW



Equivalent Circuit



TOP VIEW

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V_{DSS}	20	V
Gate-Source Voltage	V_{GSS}	±12	V
Drain Current (Note 1)	I_D	5.9	A
Pulsed Drain Current (Note 4)	I_{DM}	21	A

Thermal Characteristics

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 1)	P_D	1.4	W
Thermal Resistance, Junction to Ambient (Note 1)	$R_{\theta JA}$	90	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Notes:
1. Device mounted on FR-4 PCB, on 2oz Copper pad layout with $R_{\theta JA}$ = 90°C/W.
2. No purposefully added lead. Halogen and Antimony Free.
3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
4. Repetitive rating, pulse width limited by junction temperature.

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Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)						
Drain-Source Breakdown Voltage	BV_{DSS}	20	—	—	V	V_{GS} = 0V, I_D = 250μA
Zero Gate Voltage Drain Current	I_{DSS}	—	—	1	μA	V_{DS} = 20V, V_{GS} = 0V
Gate-Source Leakage	I_{GSS}	—	—	±100	nA	V_{GS} = ±12V, V_{DS} = 0V
ON CHARACTERISTICS (Note 5)						
Gate Threshold Voltage	$V_{GS(th)}$	0.45	—	1.4	V	V_{DS} = V_{GS}, I_D = 250μA
Static Drain-Source On-Resistance	$R_{DS\ (ON)}$	—	24	29	mΩ	V_{GS} = 4.5V, I_D = 5.0A
			42	50		V_{GS} = 2.5V, I_D = 3.1A
			68	100		V_{GS} = 2.0V, I_D = 1.5A
Forward Transfer Admittance	$\|Y_{fs}\|$	—	8	—	S	V_{DS} =5V, I_D = 2.1A
Diode Forward Voltage (Note 5)	V_{SD}	—	0.9	1.4	V	V_{GS} = 0V, I_S = 2.0A
DYNAMIC CHARACTERISTICS						
Input Capacitance	C_{iss}	—	532	—	pF	V_{DS} = 10V, V_{GS} = 0V f = 1.0MHz
Output Capacitance	C_{oss}	—	144	—	pF	
Reverse Transfer Capacitance	C_{rss}	—	117	—	pF	
Gate Resistance	R_G	—	1.3	—	Ω	V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz
SWITCHING CHARACTERISTICS						
Total Gate Charge	Q_g	—	6.7	—	nC	V_{DS} = 10V, V_{GS} = 4.5V, I_D = 5.0A
Gate-Source Charge	Q_{gs}	—	0.8	—		V_{DS} = 10V, V_{GS} = 4.5V, I_D = 5.0A
Gate-Drain Charge	Q_{gd}	—	3.0	—		V_{DS} = 10V, V_{GS} = 4.5V, I_D = 5.0A

Notes: 5. Short duration pulse test used to minimize self-heating effect.
6. Product manufactured with Green Molding Compound and does not contain Halogens or Sb_2O_3 Fire Retardants.

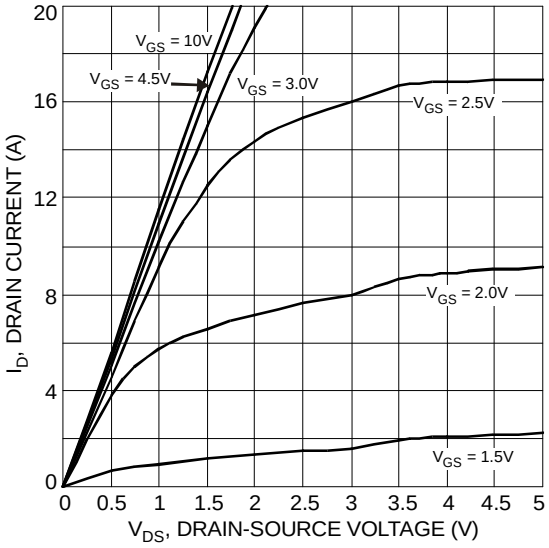

Fig. 1 Typical Output Characteristic

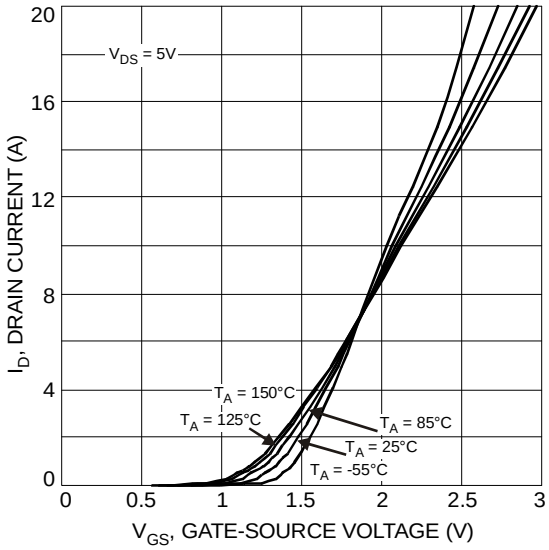

Fig. 2 Typical Transfer Characteristic

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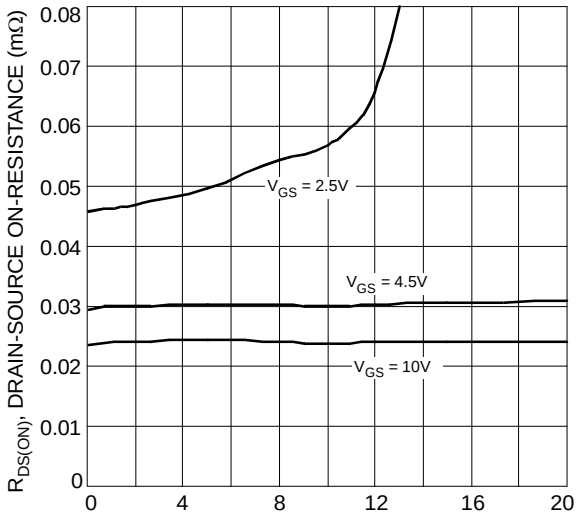

Fig. 3 Typical On-Resistance
vs. Drain Current and Gate Voltage

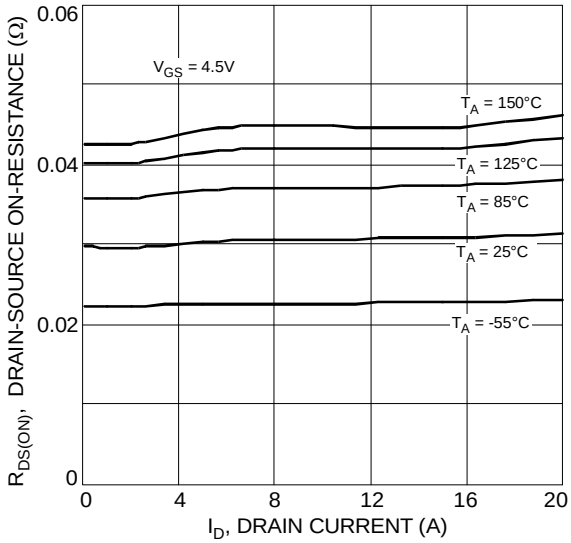

Fig. 4 Typical On-Resistance
vs. Drain Current and Temperature

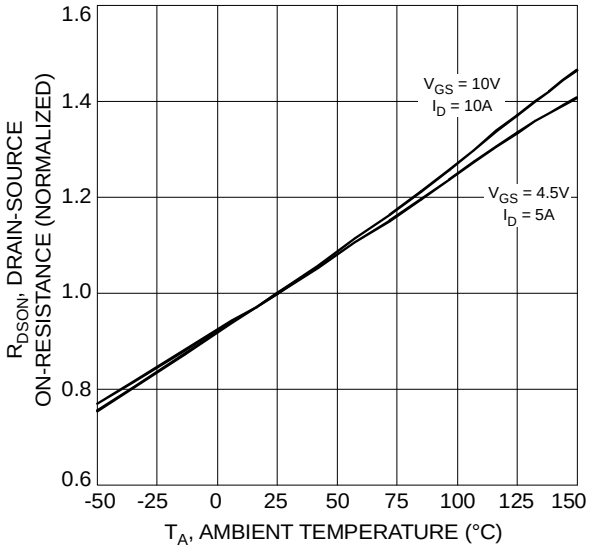

Fig. 5 On-Resistance Variation with Temperature

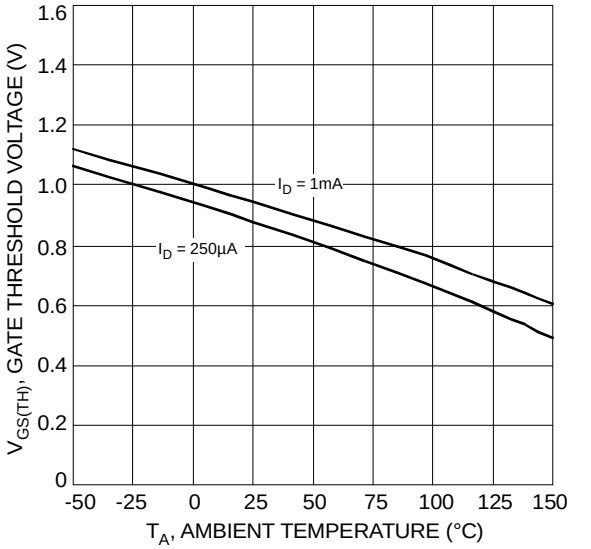

Fig. 6 Gate Threshold Variation vs. Ambient Temperature

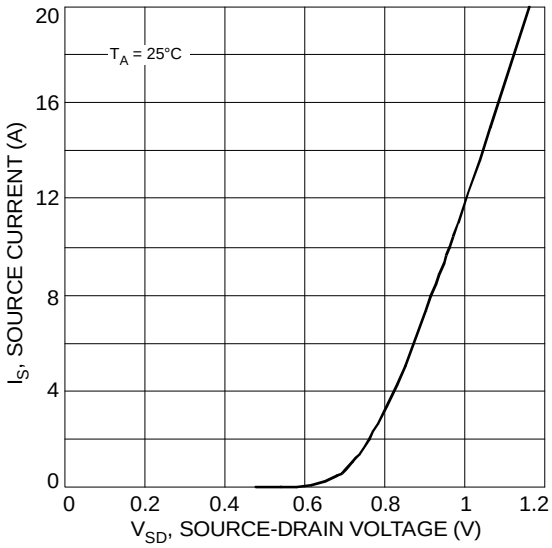

Fig. 7 Diode Forward Voltage vs. Current

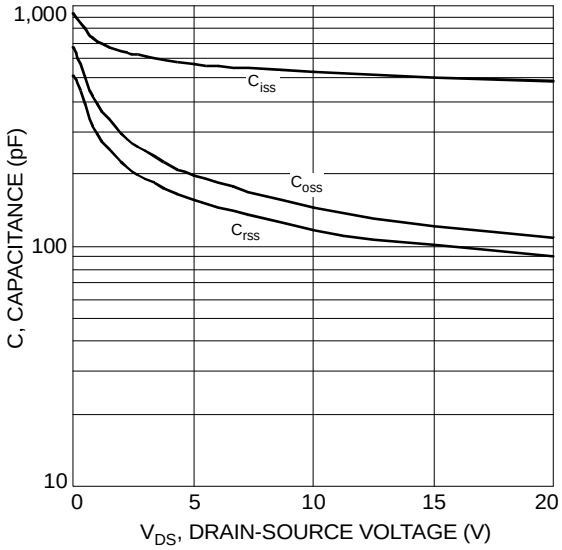

Fig. 8 Typical Total Capacitance

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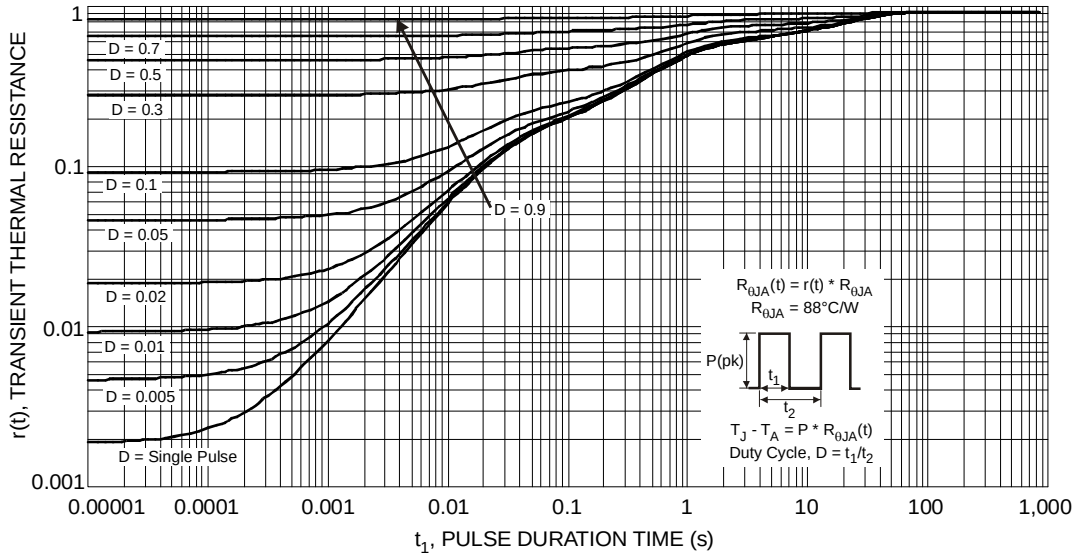


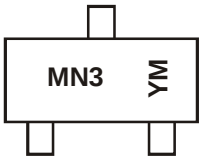
Fig. 9 Transient Thermal Response

Ordering Information (Note 7)

Part Number	Case	Packaging
DMN2050L-7	SOT-23	3000/Tape & Reel

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



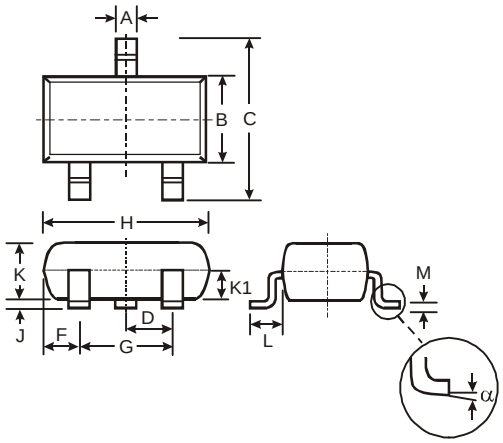
MN3 = Marking Code
YM = Date Code Marking
Y = Year (ex: V = 2008)
M = Month (ex: 9 = September)

Date Code Key

Year	2008	2009	2010	2011	2012	2013	2014	2015
Code	V	W	X	Y	Z	A	B	C

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

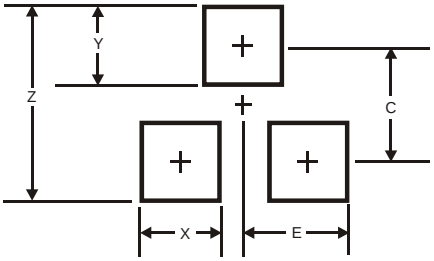
Package Outline Dimensions



SOT-23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.903	1.10	1.00
K1	-	-	0.400
L	0.45	0.61	0.55
M	0.085	0.18	0.11
α	0°	8°	-
All Dimensions in mm			

NEW PRODUCT

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits,General Dynamics и др.);

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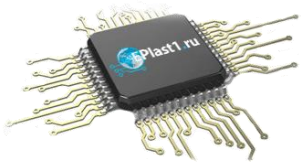
- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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